COMPLIANT

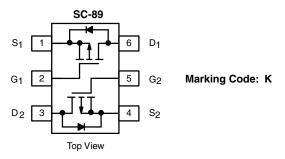
HALOGEN

FREE



P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (mA)				
- 20	8 at V _{GS} = - 4.5 V	- 150				
	12 at V _{GS} = - 2.5 V	- 125				
	15 at V _{GS} = - 1.8 V	- 100				
	20 at V _{GS} = - 1.5 V	- 30				



Ordering Information: Si1033X-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET: 1.5 V Rated
- High-Side Switching
 Low On-Resistance: 8 Ω
 Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 45 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
 Compliant to RoHS Directive 2002/95/EC

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- · Low-Voltage Operation
- · High-Speed Circuits
- Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- · Battery Operated Systems
- · Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)								
Parameter		Symbol	5 s	Steady State	Unit			
Drain-Source Voltage		V_{DS}	- 20		٧			
Gate-Source Voltage		V _{GS}	± 5					
Continuous Dunin Courant /T 450 °C\	T _A = 25 °C	I _D	- 155	- 145				
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 110	- 105				
Pulsed Drain Current ^b		I _{DM}	- 650		mA			
Continuous Source Current (Diode Conduction) ^a		I _S	- 450	- 380				
M	T _A = 25 °C	P _D	280	250	mW			
Maximum Power Dissipation ^a	T _A = 85 °C		145	130				
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C			
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V			

Notes

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

Vishay Siliconix



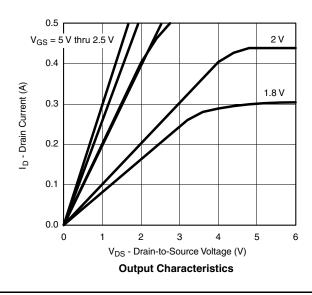
SPECIFICATIONS (T _A = Parameter	Symbol			Typ. ^a	Max.	Unit	
Static	Syllibol	rest conditions	IVIIII.	Typ.	IVIAX.	Onit	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 0.40		- 1.20	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$		± 0.5	± 1	μА	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 1	± 2		
Zero Gate Voltage Drain Current		V _{DS} = - 16 V, V _{GS} = 0 V		- 1	- 500	nA	
	I _{DSS}	V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 85 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 200			mA	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 150 mA			8		
		V _{GS} = - 2.5 V, I _D = - 125 mA			12	Ω	
		V _{GS} = - 1.8 V, I _D = - 100 mA			15		
		V _{GS} = - 1.5 V, I _D = - 30 mA			20		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 150 mA		0.4		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 150 mA, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			1500			
Gate-Source Charge	Q_{gs}	V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 150 mA		150		рС	
Gate-Drain Charge	Q_{gd}			450			
Turn-On Delay Time	t _{d(on)}				55		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 65 Ω I_D \cong - 150 mA, V_{GEN} = - 4.5 V, R_g = 10 Ω			30	ns	
Turn-Off Delay Time	t _{d(off)}				60		
Fall Time	t _f				30		

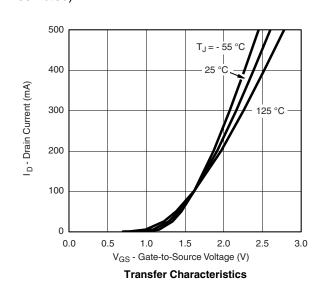
Notes:

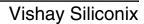
- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

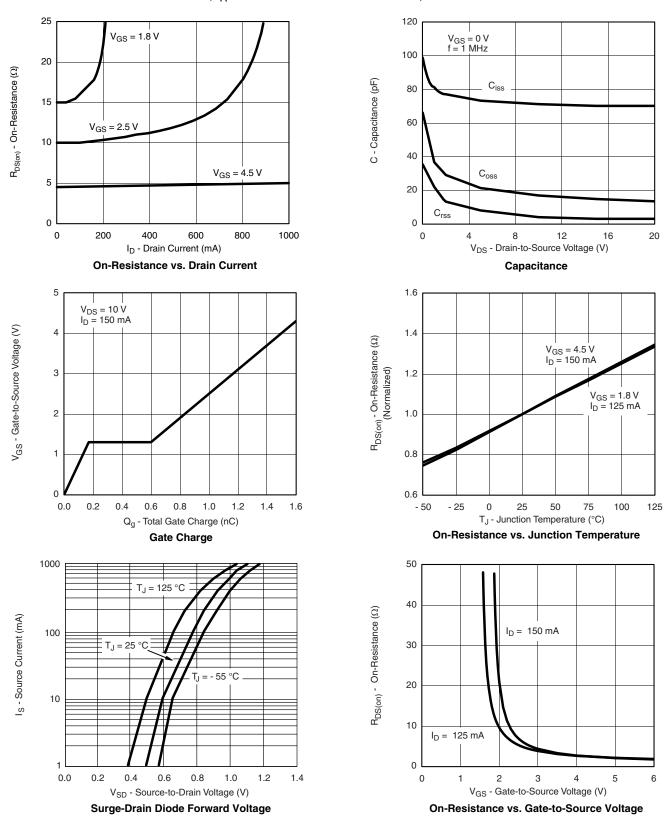








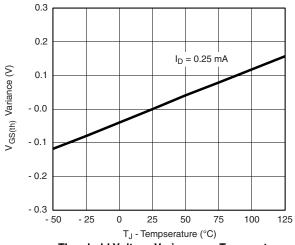
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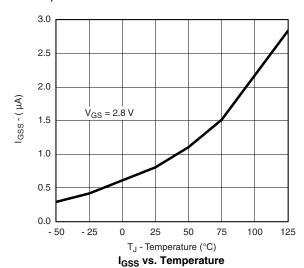


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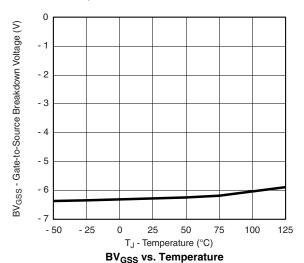


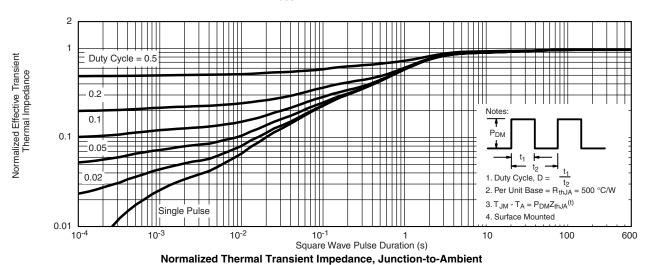
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted)





Threshold Voltage Variance vs. Temperature





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Revision: 02-Oct-12 Document Number: 91000

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SI1033X-T1-GE3